

KOI-6006B

Features

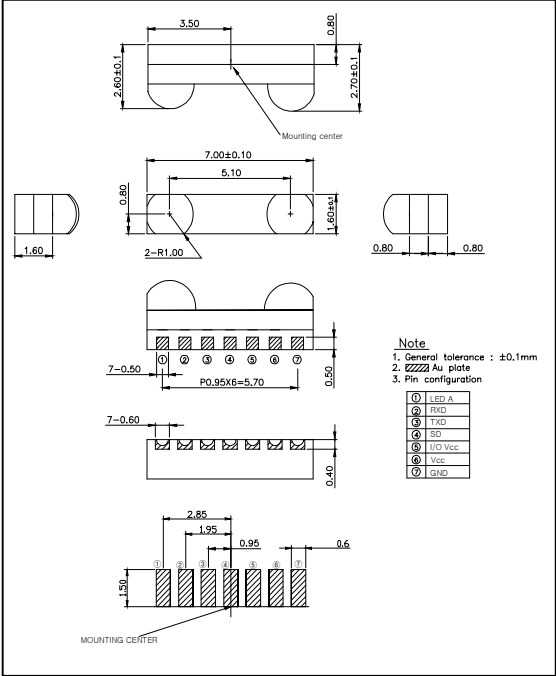
- Compliant to IrDA 1.4 Low Power Standard
- Wide Voltage Operation : 2.4 ~ 3.6V
- Compact Package Integrated Transmitter and Receiver
(7.0L x 2.75W x 1.6T)
- Complete Power Down Mode for the Current Consumption.
- Lead-free & High reliability package
- LED Stuck-high Protection

Applications

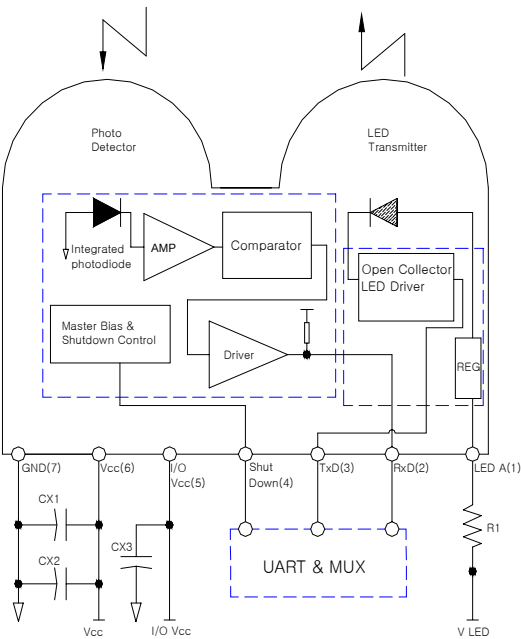
- Cellular Phone
- Personal Computer(Desk-top PC, Lap-top PC)
- Printers, Vending Machine, ATM
- Personal Digital Assistants.(PDA)

Dimensions

(Unit : mm)



Block Diagram



Component	Resistor Value	LED Voltage
R1	2.7 Ω ±5%, 0.0625Watt	VLED = 2.4 V
	3.3 Ω ±5%, 0.0625Watt	VLED = 2.7 V
	4.7 Ω ±5%, 0.0625Watt	VLED = 3.0 V
	5.6 Ω ±5%, 0.0625Watt	3.0V < VLED < 3.6V
	6.8 Ω ±5%, 0.0625Watt	VLED = 3.6 V
	10 Ω ±5%, 0.0625Watt	3.0V < VLED < 4.2V
CX1,CX3	0.47uF ±20% Ceramic	
CX2	6.8uF ±20% Tantalum or Ceramic	

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Absolute Maximum Ratings

[Ta = 25 °C]

Parameter	Symbol	Conditions	Min.	Max.	Unit
Supply Voltage	V _{CC}	-	0	6.5	V
LED Supply Voltage	V _{LED}	-	0	6.0	V
Operating Temperature	T _{opr.}	-	-20	85	°C
Storage Temperature	T _{stg.}	-	-40	100	°C
DC LED Transmit Current	I _{LED} (DC)	-	-	50	mA
Peak LED Transmit Current	I _{LED} (PK)	<90μs pulse width, <20% duty cycle	-	200	mA
Receiver Data Output Voltage	V _{RxD}	-	-0.5	V _{CC} +0.5	V
Transmitter Data Input Voltage	V _{TxD}	-	-0.5	V _{CC} +0.5	V
Data Rate	BR	-	9.6	115.2	Kbit/s

4. Electro-Optical Characteristics

[Ta=25 °C, V_{CC}=3.3V]

Parameter		Symbol	Conditions	Min.	Typ.	Max.	Unit
Supply Current		I _{cc1}	Shutdown	-	-	0.5	μA
		I _{cc2}	Idle	-	90	150	μA
Transmitter	Transmitter Wakeup Time	T _{tw}		-	15	20	μs
	Viewing Angle	2Θ _{1/2}	-	30	-	60	deg.
	Data Output Pulse Width	T _{stp} w	tpw(RxD)=1.63μs at 115.2kbit/s	1.6	1.7	1.8	μs
	Rise Time	t _r	BR=115.2kbit/s	-	50	100	ns
	Fall Time	t _f		-	100	150	ns
	Peak Emission Wavelength	λ _p	-	-	875	-	nm
	Spectral Bandwidth	Δλ	-	-	45	-	nm
Receiver	Viewing Angle	2Θ _{1/2}	-	30	-	60	deg.
	Peak Sensitivity Wavelength	λ _p	-	-	880	-	nm
	High Level Output Voltage	V _{OH}	I _{OH} =-20μA	V _{CC} -0.2	-	-	V
	Low Level Output Voltage	V _{OL}	I _{OL} =1mA	-	-	0.4	V
	Rx SIR Pulse Width	T _{srp} w	tpw(RxD)=1.63μs at 115.2kbit/s	1	2.2	4	μs
	Rise Time	t _r	BR=115.2kbit/s	-	50	100	ns
	Fall Time	t _f		-	50	100	ns
	Communication Distance	D		20	60	-	cm
	Receiver Latency Time	T _L		-	60	200	μs
	Receiver Wakeup Time	T _{rw}		-	50	100	μs